

74HC2G02; 74HCT2G02

Dual 2-input NOR gate

Rev. 04 — 11 May 2009

Product data sheet

1. General description

The 74HC2G02 and 74HCT2G02 are high-speed Si-gate CMOS devices. They provide two 2-input NOR gates.

The HC device has CMOS input switching levels and supply voltage range 2 V to 6 V.

The HCT device has TTL input switching levels and supply voltage range 4.5 V to 5.5 V.

2. Features

- Wide supply voltage range from 2.0 V to 6.0 V
- Symmetrical output impedance
- High noise immunity
- Low power dissipation
- Balanced propagation delays
- Multiple package options
- ESD protection:
 - ◆ HBM JESD22-A114E exceeds 2000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
- Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ and $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$

3. Ordering information

Table 1. Ordering information

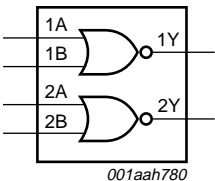
| Type number | Package | | | |
|---------------------------|---|--------|---|----------|
| | Temperature range | Name | Description | Version |
| 74HC2G02DP 74HCT2G02DP | $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$ | TSSOP8 | plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm | SOT505-2 |
| 74HC2G02DC 74HCT2G02DC | $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$ | VSSOP8 | plastic very thin shrink small outline package; 8 leads; body width 2.3 mm | SOT765-1 |
| 74HC2G02GD 74HCT2G02GD | $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$ | XSON8U | plastic extremely thin small outline package; no leads; 8 terminals; UTLP based; body $3 \times 2 \times 0.5$ mm | SOT996-2 |

4. Marking

Table 2. Marking code

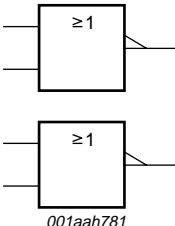
| Type number | Marking code |
|-------------|--------------|
| 74HC2G02DP | H02 |
| 74HCT2G02DP | T02 |
| 74HC2G02DC | H02 |
| 74HCT2G02DC | T02 |
| 74HC2G02GD | H02 |
| 74HCT2G02GD | T02 |

5. Functional diagram



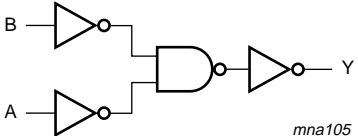
001aah780

Fig 1. Logic symbol



001aah781

Fig 2. IEC logic symbol

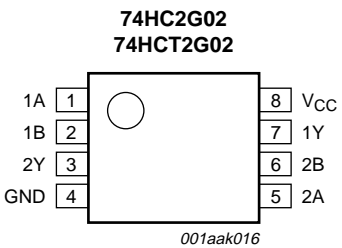


mna105

Fig 3. Logic diagram (one gate)

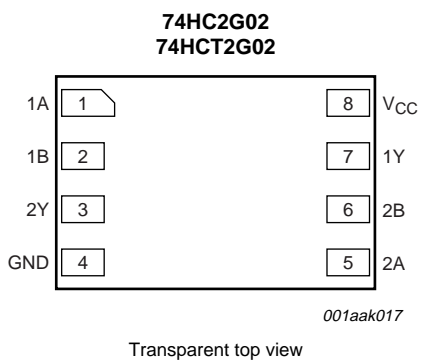
6. Pinning information

6.1 Pinning



001aak016

Fig 4. Pin configuration SOT505-2 (TSSOP8) and SOT765-1 (VSSOP8)



001aak017

Transparent top view

Fig 5. Pin configuration SOT996-2 (XSON8U)

6.2 Pin description

Table 3. Pin description

| Symbol | Pin | Description |
|-----------------|------|----------------|
| 1A, 2A | 1, 5 | data input |
| 1B, 2B | 2, 6 | data input |
| GND | 4 | ground (0 V) |
| 1Y, 2Y | 7, 3 | data output |
| V _{CC} | 8 | supply voltage |

7. Functional description

Table 4. Function table^[1]

| Input | | Output |
|-------|----|--------|
| nA | nB | nY |
| L | L | H |
| L | H | L |
| H | L | L |
| H | H | L |

[1] H = HIGH voltage level; L = LOW voltage level.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|---------------------------|--|---------|------|------|
| V _{CC} | supply voltage | | -0.5 | +7.0 | V |
| I _{IK} | input clamping current | $V_I < -0.5 \text{ V}$ or $V_I > V_{CC} + 0.5 \text{ V}$ | [1] - | ±20 | mA |
| I _{OK} | output clamping current | $V_O < -0.5 \text{ V}$ or $V_O > V_{CC} + 0.5 \text{ V}$ | [1] - | ±20 | mA |
| I _O | output current | $V_O = -0.5 \text{ V}$ to $(V_{CC} + 0.5 \text{ V})$ | [1] - | 25 | mA |
| I _{CC} | supply current | | [1] - | 50 | mA |
| I _{GND} | ground current | | [1] -50 | - | mA |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| P _D | dynamic power dissipation | T _{amb} = -40 °C to +125 °C | [2] - | 300 | mW |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For TSSOP8 package: above 55 °C the value of P_{tot} derates linearly with 2.5 mW/K.
 For VSSOP8 package: above 110 °C the value of P_{tot} derates linearly with 8 mW/K.
 For XSON8U package: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | 74HC2G02 | | | 74HCT2G02 | | | Unit |
|------------------|-------------------------------------|-------------------------|----------|------|-----------------|-----------|------|-----------------|------|
| | | | Min | Typ | Max | Min | Typ | Max | |
| V _{CC} | supply voltage | | 2.0 | 5.0 | 6.0 | 4.5 | 5.0 | 5.5 | V |
| V _I | input voltage | | 0 | - | V _{CC} | 0 | - | V _{CC} | V |
| V _O | output voltage | | 0 | - | V _{CC} | 0 | - | V _{CC} | V |
| T _{amb} | ambient temperature | | -40 | +25 | +125 | -40 | +25 | +125 | °C |
| Δt/ΔV | input transition rise and fall rate | V _{CC} = 2.0 V | - | - | 625 | - | - | - | ns/V |
| | | V _{CC} = 4.5 V | - | 1.67 | 139 | - | 1.67 | 139 | ns/V |
| | | V _{CC} = 6.0 V | - | - | 83 | - | - | - | ns/V |

10. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | -40 °C to +85 °C | | | -40 °C to +125 °C | | Unit |
|-----------------|---------------------------|---|------------------|--------------------|------|-------------------|------|------|
| | | | Min | Typ ^[1] | Max | Min | Max | |
| 74HC2G02 | | | | | | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 2.0 V | 1.5 | 1.2 | - | 1.5 | - | V |
| | | V _{CC} = 4.5 V | 3.15 | 2.4 | - | 3.15 | - | V |
| | | V _{CC} = 6.0 V | 4.2 | 3.2 | - | 4.2 | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 2.0 V | - | 0.8 | 0.5 | - | 0.5 | V |
| | | V _{CC} = 4.5 V | - | 2.1 | 1.35 | - | 1.35 | V |
| | | V _{CC} = 6.0 V | - | 2.8 | 1.8 | - | 1.8 | V |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} | | | | | | |
| | | I _O = -20 μA; V _{CC} = 2.0 V | 1.9 | 2.0 | - | 1.9 | - | V |
| | | I _O = -20 μA; V _{CC} = 4.5 V | 4.4 | 4.5 | - | 4.4 | - | V |
| | | I _O = -20 μA; V _{CC} = 6.0 V | 5.9 | 6.0 | - | 5.9 | - | V |
| | | I _O = -4.0 mA; V _{CC} = 4.5 V | 4.13 | 4.32 | - | 3.7 | - | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | | | | | | |
| | | I _O = 20 μA; V _{CC} = 2.0 V | - | 0 | 0.1 | - | 0.1 | V |
| | | I _O = 20 μA; V _{CC} = 4.5 V | - | 0 | 0.1 | - | 0.1 | V |
| | | I _O = 20 μA; V _{CC} = 6.0 V | - | 0 | 0.1 | - | 0.1 | V |
| | | I _O = 4.0 mA; V _{CC} = 4.5 V | - | 0.15 | 0.33 | - | 0.4 | V |
| I _I | input leakage current | V _I = V _{CC} or GND; V _{CC} = 6.0 V | - | - | ±1.0 | - | ±1.0 | μA |
| | | I _O = 0 A; V _{CC} = 6.0 V | - | - | 10 | - | 20 | μA |
| I _{CC} | supply current | per input pin; V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 6.0 V | - | - | 10 | - | 20 | μA |
| C _I | input capacitance | | - | 1.5 | - | - | - | pF |

Table 7. Static characteristics ...continued
 Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | -40 °C to +85 °C | | | -40 °C to +125 °C | | Unit |
|------------------|---------------------------|---|------------------|--------------------|------|-------------------|------|------|
| | | | Min | Typ ^[1] | Max | Min | Max | |
| 74HCT2G02 | | | | | | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 4.5 V to 5.5 V | 2.0 | 1.6 | - | 2.0 | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 4.5 V to 5.5 V | - | 1.2 | 0.8 | - | 0.8 | V |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} | | | | | | |
| | | I _O = -20 μA; V _{CC} = 4.5 V | 4.4 | 4.5 | - | 4.4 | - | V |
| | | I _O = -4.0 mA; V _{CC} = 4.5 V | 4.13 | 4.32 | - | 3.7 | - | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | | | | | | |
| | | I _O = 20 μA; V _{CC} = 4.5 V | - | 0 | 0.1 | - | 0.1 | V |
| | | I _O = 4.0 mA; V _{CC} = 4.5 V | - | 0.15 | 0.33 | - | 0.4 | V |
| I _I | input leakage current | V _I = V _{CC} or GND; V _{CC} = 5.5 V | - | - | ±1.0 | - | ±1.0 | μA |
| I _{CC} | supply current | V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 5.5 V | - | - | 10 | - | 20 | μA |
| ΔI _{CC} | additional supply current | per input; V _{CC} = 4.5 V to 5.5 V; V _I = V _{CC} - 2.1 V; I _O = 0 A | - | - | 375 | - | 410 | μA |
| C _I | input capacitance | | - | 1.5 | - | - | - | pF |

[1] All typical values are measured at T_{amb} = 25 °C.

11. Dynamic characteristics

Table 8. Dynamic characteristics
 Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 7](#).

| Symbol | Parameter | Conditions | -40 °C to +85 °C | | | -40 °C to +125 °C | | Unit |
|-----------------|-------------------------------|--|------------------|--------------------|-----|-------------------|-----|------|
| | | | Min | Typ ^[1] | Max | Min | Max | |
| 74HC2G02 | | | | | | | | |
| t _{pd} | propagation delay | nA and nB to nY; see Figure 6 ^[2] | | | | | | |
| | | V _{CC} = 2.0 V | - | 26 | 95 | - | 110 | ns |
| | | V _{CC} = 4.5 V | - | 9 | 19 | - | 22 | ns |
| | | V _{CC} = 5.0 V; C _L = 15 pF | - | 9 | - | - | - | ns |
| | | V _{CC} = 6.0 V | - | 8 | 16 | - | 20 | ns |
| t _t | transition time | see Figure 6 ^[3] | | | | | | |
| | | V _{CC} = 2.0 V | - | 19 | 95 | - | 125 | ns |
| | | V _{CC} = 4.5 V | - | 7 | 19 | - | 25 | ns |
| | | V _{CC} = 6.0 V | - | 5 | 16 | - | 20 | ns |
| C _{PD} | power dissipation capacitance | V _I = GND to V _{CC} ^[4] | - | 10 | - | - | - | pF |

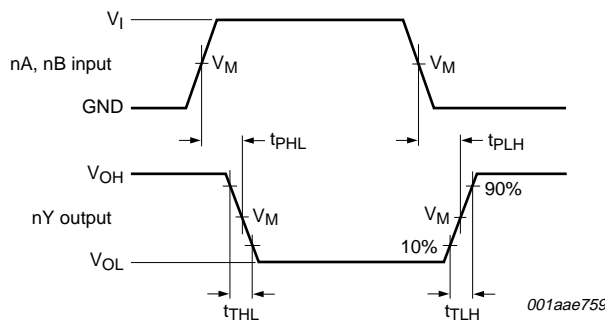
Table 8. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 7](#).

| Symbol | Parameter | Conditions | -40 °C to +85 °C | | | -40 °C to +125 °C | | Unit |
|------------------|-------------------------------|---|------------------|--------------------|-----|-------------------|-----|------|
| | | | Min | Typ ^[1] | Max | Min | Max | |
| 74HCT2G02 | | | | | | | | |
| t _{pd} | propagation delay | nA and nB to nY; see Figure 6 | | | | | | |
| | | V _{CC} = 4.5 V | - | 12 | 24 | - | 29 | ns |
| | | V _{CC} = 5.0 V; C _L = 15 pF | - | 12 | - | - | - | ns |
| t _t | transition time | V _{CC} = 4.5 V; see Figure 6 | - | 6 | 19 | - | 22 | ns |
| C _{PD} | power dissipation capacitance | V _I = GND to V _{CC} - 1.5 V | - | 10 | - | - | - | pF |

- [1] All typical values are measured at T_{amb} = 25 °C.
- [2] t_{pd} is the same as t_{PLH} and t_{PHL}.
- [3] t_t is the same as t_{TLH} and t_{THL}.
- [4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:
 f_i = input frequency in MHz;
 f_o = output frequency in MHz;
 C_L = output load capacitance in pF;
 V_{CC} = supply voltage in V;
 N = number of inputs switching;
 Σ(C_L × V_{CC}² × f_o) = sum of outputs.

12. Waveforms



Measurement points are given in [Table 9](#).
 VOL and VOH are typical output voltage levels that occur with the output load.

Fig 6. Propagation delay data input (nA, nB) to data output (nY) and transition time output (nY)

Table 9. Measurement points

| Type | Input | Output |
|-----------|-----------------------|-----------------------|
| | V _M | V _M |
| 74HC2G02 | 0.5 × V _{CC} | 0.5 × V _{CC} |
| 74HCT2G02 | 1.3 V | 1.3 V |



Test data is given in [Table 10](#).

Definitions for test circuit:

R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

C_L = Load capacitance including jig and probe capacitance.

R_L = Load resistance.

S1 = Test selection switch.

Fig 7. Load circuit for measuring switching times

Table 10. Test data

| Type | Input | | Load | | S1 position |
|-----------|-----------------|-------------|--------------|--------------|--------------------|
| | V_I | t_r, t_f | C_L | R_L | t_{PHL}, t_{PLH} |
| 74HC2G02 | GND to V_{CC} | ≤ 6 ns | 15 pF, 50 pF | 1 k Ω | open |
| 74HCT2G02 | GND to 3 V | ≤ 6 ns | 15 pF, 50 pF | 1 k Ω | open |

13. Package outline

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm SOT505-2

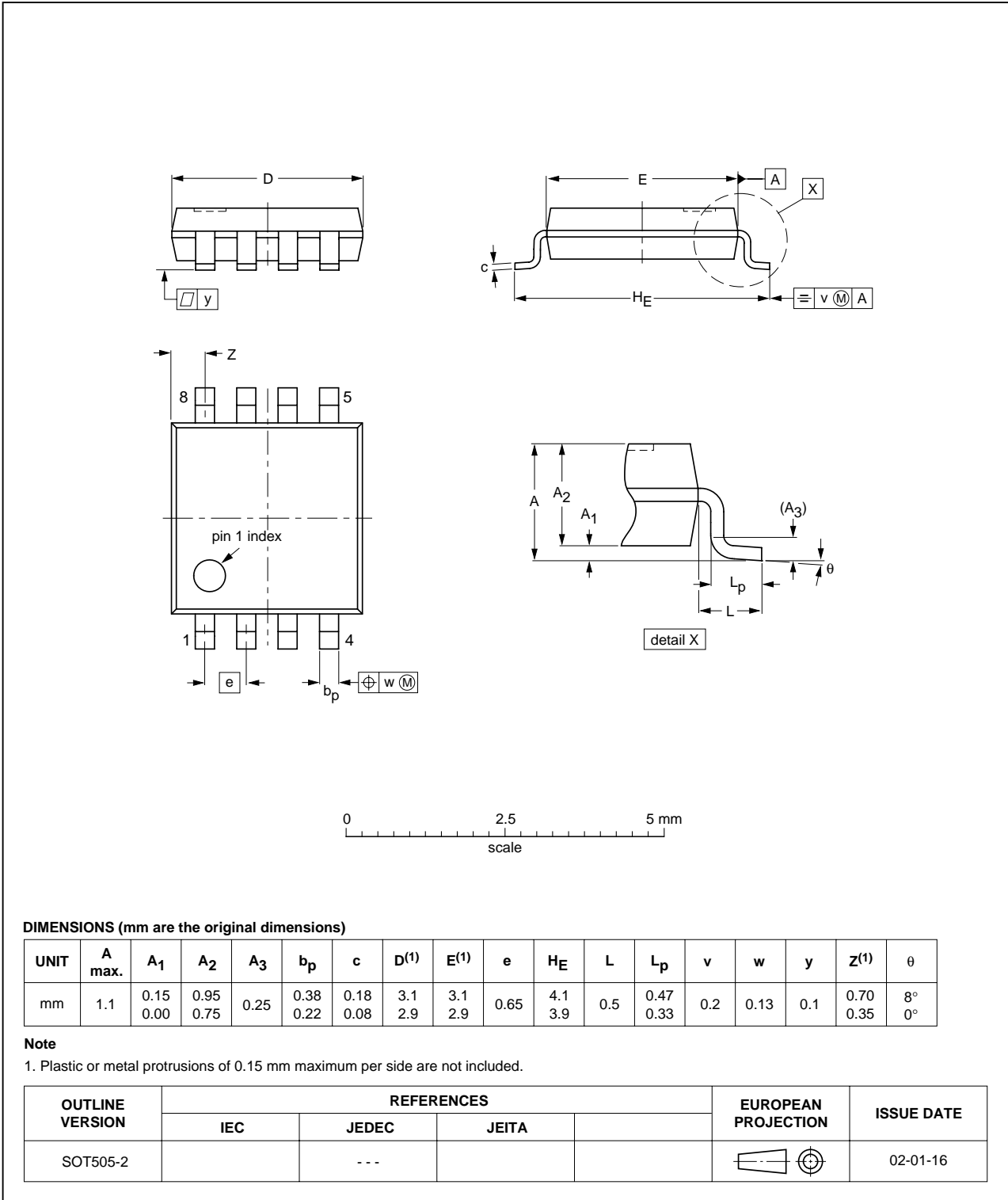


Fig 8. Package outline SOT505-2 (TSSOP8)

VSSOP8: plastic very thin shrink small outline package; 8 leads; body width 2.3 mm

SOT765-1

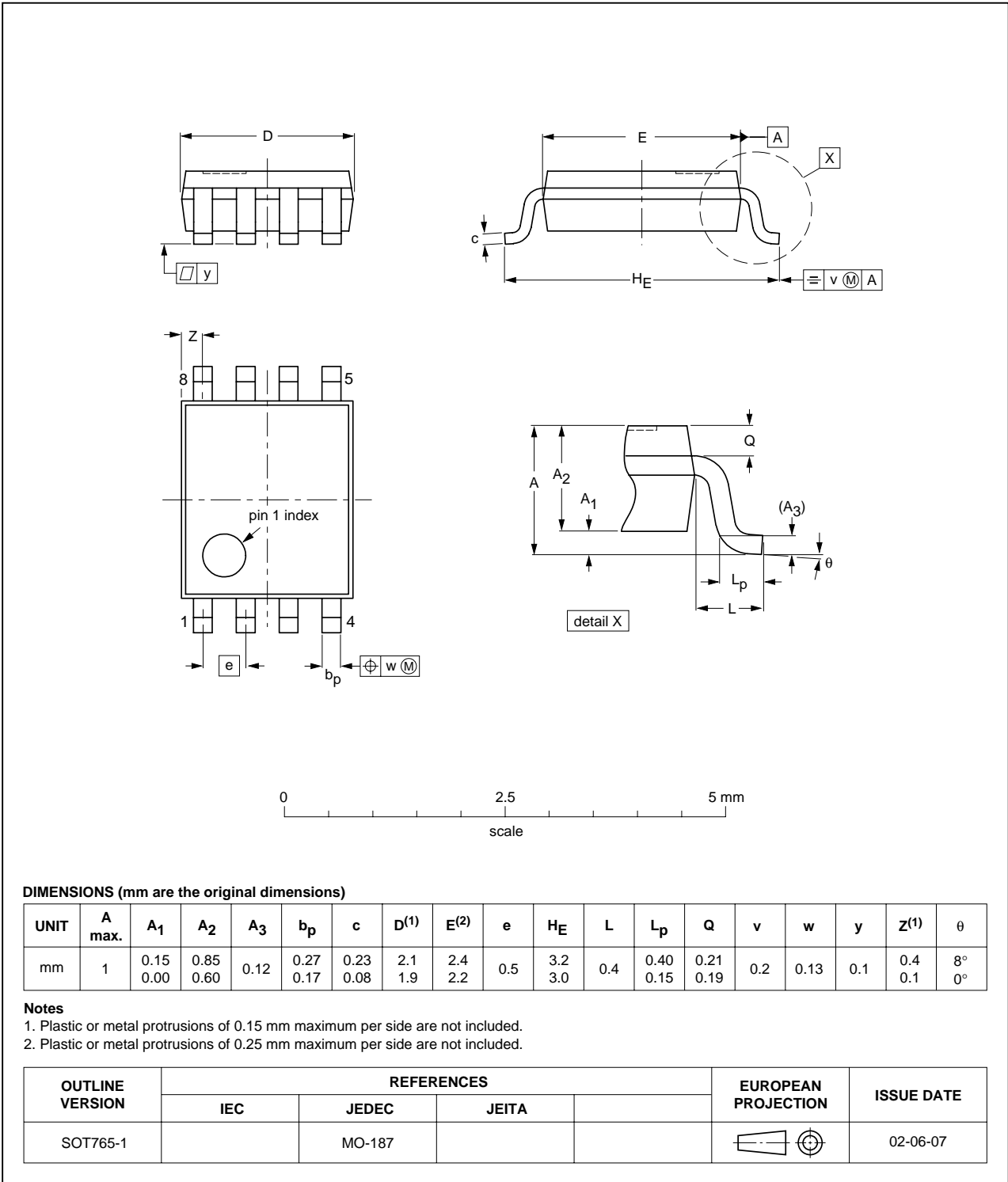


Fig 9. Package outline SOT765-1 (VSSOP8)

XSON8U: plastic extremely thin small outline package; no leads;
8 terminals; UTLP based; body 3 x 2 x 0.5 mm

SOT996-2



Fig 10. Package outline SOT996-2 (XSON8U)

14. Abbreviations

Table 11. Abbreviations

| Acronym | Description |
|---------|---|
| CMOS | Complementary Metal Oxide Semiconductor |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| MM | Machine Model |
| TTL | Transistor-Transistor Logic |

15. Revision history

Table 12. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|--|-----------------------|---------------|----------------|
| 74HC_HCT2G02_4 | 20090511 | Product data sheet | - | 74HC_HCT2G02_3 |
| Modifications: | <ul style="list-style-type: none"> The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate. Added type number 74HC2G02GD and 74HCT2G02GD (XSON8U package) | | | |
| 74HC_HCT2G02_3 | 20030514 | Product data sheet | - | 74HC_HCT2G02_2 |
| 74HC_HCT2G02_2 | 20030203 | Product specification | - | 74HC_HCT2G02_1 |
| 74HC_HCT2G02_1 | 20020710 | Product specification | - | - |

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16.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
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[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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